

**Figure 1.** a)  $SiO_2$  thickness as a function of the selective spatial ALD cycles for the first supercycle: (•) on the growth area as measured by spectroscopic ellipsometry (SE); (•) on the non-growth area (ZnO) as measured by SE; (•) on the non-growth area as measured and by low energy ion spectroscopy, LEIS. b),  $SiO_2$  thickness values after a 3 seconds reactive ion etching correction step.